

ESDR0502NMUTAG

Data Sheet

TVS Diode Arrays

Manufacturers ON Semiconductor, LLC

Package/Case uDFN-6

Product Type Circuit Protection

RoHS Rohs

Lifecycle



Images are for reference only

Please submit RFQ for ESDR0502NMUTAG or Email to us; sales@ovaga.com We will contact you in 12 hours.



General Description

The ESDR0502N ultra low capacitance array is designed to protect high speed data lines from ESD.Ultra-low capacitance and high level of ESD protection makes this device well suited for use in USB 2.0 applications.

Features Application

Low Capacitance (0.3 pF Typical Between I/O Lines and Ground)

ONSEMI

ESD Rating of Class 3B (Exceeding 8 kV) per Human Body Model and Class C (Exceeding 400 V) per Machine Model

Protection for the Following IEC Standards:IEC 61000-4-2 8 kV (contact)

UL Flammability Rating of 94 V-0

These Devices are Pb-Free and are RoHS Compliant

Related Products



ESD8011MUT5G

ON Semiconductor, LLC

X3DFN-2



SZESD7016MUTAG
ON Semiconductor, LLC
UDFN



SZESD7004MUTAG

ON Semiconductor, LLC UDFN-10



ESD7504MUTAG

ON Semiconductor, LLC UFDN-10





ON Semiconductor, LLC X3DFN-2



SZESD8351HT1G

ON Semiconductor, LLC 477-02



ESD7008MUTAG

ON Semiconductor, LLC uDFN-18





ON Semiconductor, LLC X3DFN2